Home Assignment # 2 ECE - 315 [Only for BTech Students]

Due Date: 11th Sept 2015

Total Marks: 10

Q1: The threshold voltage of the transistor is $V_T = 2.0$ Volts, K = 0.125 mA/V².

The capacitors are very large.

Find the small-signal gain $A_v = v_0/v_i$ of this amplifier.



Q2: For the circuit below, V_G is the DC bias at the gate, v_i is the small-signal input and v_0 the small-signal output. The transistor is known to be in the **saturation** region.

The capacitor in the circuit is extremely large.

- 1) Draw the resulting small-signal circuit.
- 2) In terms of g_m , find the small-signal gain $A_v = v_0/v_i$.

NOTE: Do **not** attempt any **DC analysis**; provide your solutions directly in terms of g_m . Ignore the output resistance (i.e., $r_o = \infty$).



Q3: The capacitor in the circuit below is very large.

Determine the small-signal voltage gain $(A_v = v_o/v_i)$ of the amplifier below.



Q4: Take the example 3.1 (solved) in your text book on page 50. Demonstrate both the curves using Eldo and Cadence Tools.

Q5: The capacitors in the circuit below are very large.

I have completed the DC analysis—I determined that V_{GS} =4.0 V, and CHECKED that the MOSFET is in saturation.

Finish the remainder of the analysis, to:

1. Determine and carefully draw the simplified small-signal circuit (be complete and precise!).

2. Determine the small-signal voltage gain $(A_v = v_0/v_i)$ of the amplifier below.

